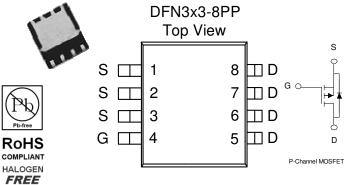
P-Channel 60-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

| • | Low r _{DS(on)} provides higher efficiency and |
|---|--|
| | extends battery life |

- Low thermal impedance copper leadframe DFN3x3-8PP saves board space
- Fast switching speed
- High performance trench technology

| PRODUCT SUMMARY | | | | |
|---------------------|------------------------|------------|--|--|
| V _{DS} (V) | $r_{DS(on)} m(\Omega)$ | $I_{D}(A)$ | | |
| -60 | $64 @ V_{GS} = -10V$ | -6.1 | | |
| -00 | $109 @ V_{GS} = -4.5V$ | -4.7 | | |



| ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED) | | | | | | |
|--|--|-----------------------------------|------------|----|--|--|
| Parameter | Symbol | Maximum | Units | | | |
| Drain-Source Voltage | | | -60 | V | | |
| Gate-Source Voltage | V_{GS} | ±20 | V | | | |
| Continuous Drain Current ^a | $T_A=25^{\circ}C$ | Τ_ | -6.1 | | | |
| Continuous Drain Current | $T_A=25^{\circ}C$ $T_A=70^{\circ}C$ | ъ | -5 | A | | |
| Pulsed Drain Current ^b | I_{DM} | ±30 | | | | |
| Continuous Source Current (Diode Conduction) ^a | I_S | -3.5 | A | | | |
| Danie Dinamaticu ^a | $T_A=25^{\circ}C$ | P_{D} | 3.8 | W | | |
| Power Dissipation ^a | $T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$ | r D | 2.0 | VV | | |
| Operating Junction and Storage Temperature Range | | T _J , T _{stg} | -55 to 150 | °C | | |

| THERMAL RESISTANCE RATINGS | | | | | | |
|--|--------------|----------------|-------|------|--|--|
| Parameter | Symbol | Maximum | Units | | | |
| a | t <= 10 sec | D | 33 | °C/W | | |
| Maximum Junction-to-Ambient ^a | Steady State | $R_{	heta JA}$ | 81 | °C/W | | |

1

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

Analog Power AM7361P

| SPECIFICATIONS (T _A = 25°C UNLESS OTHERWISE NOTED) | | | | | | | |
|---|---------------------|---|--------|------|------|--------|--|
| Parameter | Symbol | Test Conditions | Limits | | | Unit | |
| i didilietei | Symbol | rest conditions | Min | Тур | Max | ןיייין | |
| Static | | | | | | | |
| Gate-Threshold Voltage | $V_{GS(th)}$ | $V_{DS} = V_{GS}$, $I_D = -250 \text{ uA}$ | -1 | | | ٧ | |
| Gate-Body Leakage | I _{GSS} | $V_{DS} = 0 \ V, \ V_{GS} = \pm 20 \ V$ | | | ±100 | nA | |
| Zero Gate Voltage Drain Current | | $V_{DS} = -48 \text{ V}, V_{GS} = 0 \text{ V}$ | | | -1 | uA | |
| Zero Gate Voltage Drain Gunent | I _{DSS} | $V_{DS} = -48 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$ | | | -5 | | |
| On-State Drain Current ^A | $I_{D(on)}$ | $V_{DS} = -5 \text{ V}, V_{GS} = -10 \text{ V}$ | -20 | | | Α | |
| Dualis Carros On Basistana A | r | $V_{GS} = -10 \text{ V}, I_D = -6.1 \text{ A}$ | | | 64 | 0 | |
| Drain-Source On-Resistance ^A | r _{DS(on)} | $V_{GS} = -4.5 \text{ V}, I_D = -4.7 \text{ A}$ | 1(| | 109 | mΩ | |
| Forward Tranconductance ^A | g_{fs} | $V_{DS} = -15 \text{ V}, I_{D} = -6.1 \text{ A}$ | | 11 | | S | |
| Diode Forward Voltage | V_{SD} | $I_S = 3.5 \text{ A}, V_{GS} = 0 \text{ V}$ | | -0.8 | | ٧ | |
| Dynamic ^b | • | | | | | | |
| Total Gate Charge | Q_g | V 15 V V 4 5 V | | 15 | | nC | |
| Gate-Source Charge | Q_gs | $V_{DS} = -15 \text{ V}, V_{GS} = -4.5 \text{ V},$ $I_{D} = -6.1 \text{ A}$ | | 4 | | | |
| Gate-Drain Charge | Q_{gd} | 1D = -0.1 A | | 3 | | | |
| Turn-On Delay Time | $t_{d(on)}$ | | | 12 | | | |
| Rise Time | t _r | $V_{DD} = -15 \ V, \ R_L = 6 \ \Omega \ ,$ | | 9 | |] _ [| |
| Turn-Off Delay Time | t _{d(off)} | $I_D = -1 A$, $V_{GEN} = -10 V$ | | 22 | | nS | |
| Fall-Time | t _f | | | 16 | | 1 | |

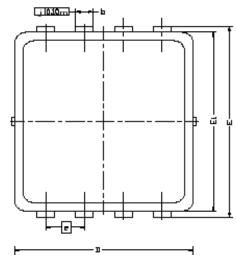
Notes

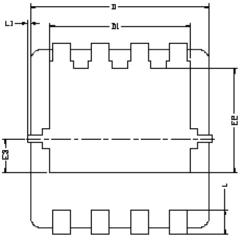
a. Pulse test: $PW \le 300$ us duty cycle $\le 2\%$.

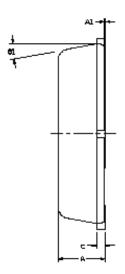
b. Guaranteed by design, not subject to production testing.

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Package Information







| DIM. | MIL | LIMETE | :RS | INCHES | | |
|--------|-----------|--------|-------|-----------|---------|--------|
| יויונת | MIN | NOM | MAX | MIN | NOM | MAX |
| Α | 0,700 | 0'80 | 0.900 | 0.0276 | 0.0315 | 0.0354 |
| A1 | 0.00 | | 0.05 | 0.000 | | 0.002 |
| b | 0.24 | 0.30 | 0.35 | 0.009 | 0.012 | 0.014 |
| C | 0.10 | 0.152 | 0.25 | 0,004 | 0,006 | 0.010 |
| ם | 3.00 BSC | | | 0.118 BSC | | |
| D1 | 2.35 B2C | | | a. | 093 BS | C 2 |
| Ε | 3,20 BSC | | | 0, | 126 BS | S. |
| E1 | 3.00 BSC | | | ٥ | .118 BS | :C |
| E5 | 1.75 BSC | | | a. | 069 BS | C 2 |
| E3 | 0.575 BSC | | | 0. | 023 BS | 3C |
| 6 | 0.65 BSC | | | Ō. | 026 BS | C 2 |
| Г | 0,30 | 0,40 | 0,50 | 0,0118 | 0.0157 | 0.0197 |
| L1 | | | 0.100 | D | | 0.004 |
| 91 | ٥° | 10* | 12* | 0* | 10* | 12* |